250V P-CHANNEL ENHANCEMENT MODE MOSFET

SUMMARY

V(BR)DSS=-250V; $RDS(ON)=14\Omega$; ID=-205mA

DESCRIPTION

This 250V enhancement mode P-channel MOSFET provides users with a competitive specification offering efficient power handling capability, high impedance and is free from thermal runaway and thermally induced secondary breakdown. Applications benefiting from this device include a variety of Telecom and general high voltage switching circuits.



FEATURES

- High voltage
- Low on-resistance
- · Fast switching speed
- Low gate drive
- Low threshold
- Complementary N-channel Type ZVN4525Z
- SOT89 package

APPLICATIONS

- · Earth Recall and dialling switches
- · Electronic hook switches
- High Voltage Power MOSFET Drivers
- Telecom call routers
- Solid state relays

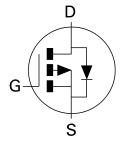
ORDERING INFORMATION

DEVICE	REEL SIZE (inches)	TAPE WIDTH (mm)	QUANTITY PER REEL
ZVP4525ZTA	7	12mm embossed	1000 units
ZVP4525ZTC	13	12mm embossed	4000 units

DEVICE MARKING

• P52









ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	LIMIT	UNIT
Drain-Source Voltage	V _{DSS}	250	V
Gate Source Voltage	V _{GS}	±40	V
Continuous Drain Current (VGS=10V; TA=25°C)(a) (VGS=10V; TA=70°C)(a)	I _D	-205 -164	mA mA
Pulsed Drain Current (c)	I _{DM}	-1	A
Continuous Source Current (Body Diode)	IS	-0.75	А
Pulsed Source Current (Body Diode)	I _{SM}	-1	А
Power Dissipation at T _A =25°C (a) Linear Derating Factor	PD	1.2 9.6	W mW/°C
Operating and Storage Temperature Range	T _j :T _{stg}	-55 to +150	°C

THERMAL RESISTANCE

PARAMETER	SYMBOL	VALUE	UNIT
Junction to Ambient (a)	$R_{\theta JA}$	103	°C/W
Junction to Ambient (b)	$R_{\theta JA}$	50	°C/W

NOTES

 $(a) For a device surface mounted on 25 mm\ x\ 25 mm\ FR4\ PCB\ with\ high\ coverage\ of\ single\ sided\ 1oz\ copper,\ in\ still\ air\ conditions$

(b) For a device surface mounted on FR4 PCB measured at t $\!\!<\!\!5$ secs.

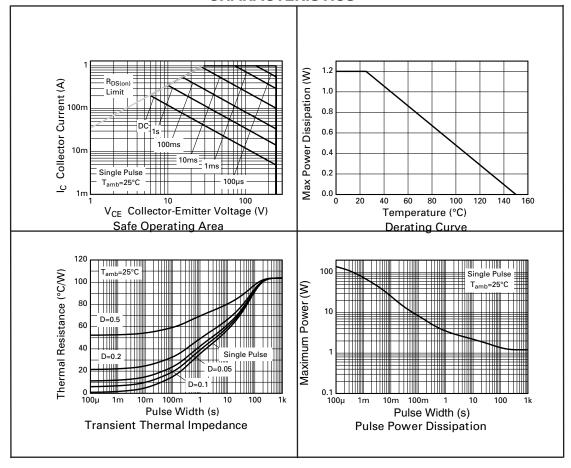
(c) Repetitive rating - pulse width limited by maximum junction temperature. Refer to Transient Thermal Impedance graph.

NB High Voltage Applications

For high voltage applications, the appropriate industry sector guidelines should be considered with regard to voltage spacing between conductors.



CHARACTERISTICS





ELECTRICAL CHARACTERISTICS (at T_{amb} = 25°C unless otherwise stated)

LLLOTTIIOAL OTTAITAOTEITIO	,	·aiiib	_ 23 (<i>-</i> 4	00 0 0	iioi iiioo otatoa,	
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.	
STATIC		!		'			
Drain-Source Breakdown Voltage	V _{(BR)DSS}	-250	-285		V	I _D =-1mA, V _G S=0V	
Zero Gate Voltage Drain Current	I _{DSS}		-30	-500	nA	V _{DS} =-250V, V _{GS} =0V	
Gate-Body Leakage	I _{GSS}		±1	±100	nA	V _{GS} =±40V, V _{DS} =0V	
Gate-Source Threshold Voltage	V _{GS(th)}	-0.8	-1.5	-2.0	V	I _D =-1mA, V _{DS} = V _{GS}	
Static Drain-Source On-State Resistance (1)	R _{DS(on)}		10 13	14 18	ΩΩ	V _{GS} =-10V, I _D =-200mA V _{GS} =-3.5V, I _D =-100mA	
Forward Transconductance (3)	9fs	80	200		mS	V _{DS} =-10V,I _D =-0.15A	
DYNAMIC (3)							
Input Capacitance	C _{iss}		73		pF	V 05 V V 0V	
Output Capacitance	Coss		12.8		pF	V _{DS} =-25 V, V _{GS} =0V, f=1MHz	
Reverse Transfer Capacitance	C _{rss}		3.91		pF		
SWITCHING(2) (3)		•	•	•			
Turn-On Delay Time	t _{d(on)}		1.53		ns		
Rise Time	t _r		3.78		ns	V _{DD} =-30V, I _D =-200m	
Turn-Off Delay Time	t _{d(off)}		17.5		ns	R _G =50Ω, V _G S=-10V (refer to test circuit)	
Fall Time	tf		7.85		ns		
Total Gate Charge	Ωg		2.45	3.45	nC		
Gate-Source Charge	Qgs		0.22	0.31	nC	V_{DS} =-25V, V_{GS} =-10V, I_{D} =-200mA(refer to	
Gate Drain Charge	Q _{gd}		0.45	0.63	nC	test circuit)	
SOURCE-DRAIN DIODE		•		'	•		
Diode Forward Voltage (1)	V _{SD}			0.97	V	T _j =25°C, I _S =-200mA, V _{GS} =0V	
Reverse Recovery Time (3)	t _{rr}		205	290	ns	Tj=25°C, IF=-200mA,	
Reverse Recovery Charge (3)	Q _{rr}		21	29	nC	di/dt=100Å/μs	

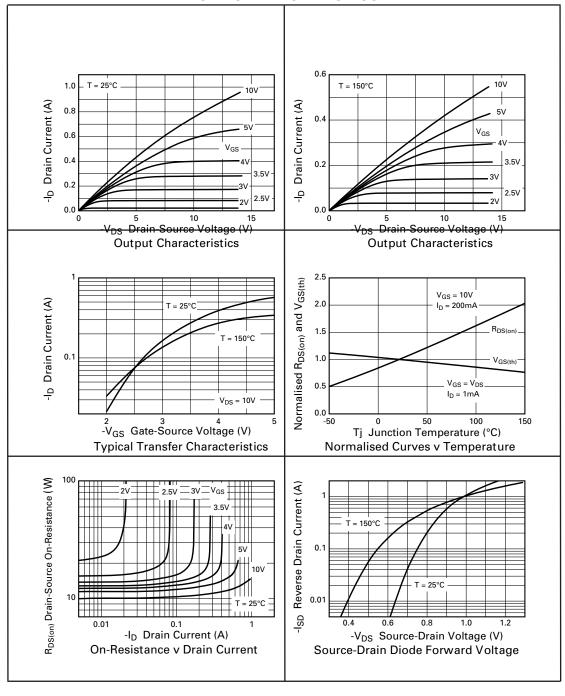
⁽¹⁾ Measured under pulsed conditions. Width=300 $\mu s.$ Duty cycle $\leq~2\%$.

⁽³⁾ For design aid only, not subject to production testing.



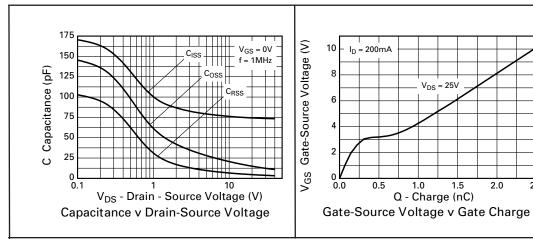
⁽²⁾ Switching characteristics are independent of operating junction temperature.

TYPICAL CHARACTERISTICS



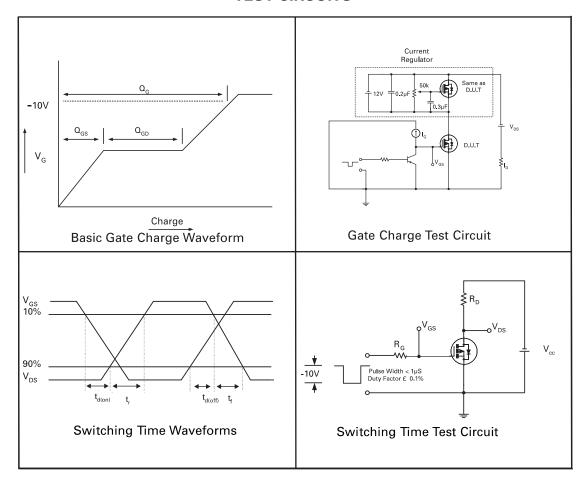


CHARACTERISTICS





TEST CIRCUITS





Definitions

Product change

Zetex Semiconductors reserves the right to alter, without notice, specifications, design, price or conditions of supply of any product or service. Customers are solely responsible for obtaining the latest relevant information before placing orders.

Applications disclaimer

The circuits in this design/application note are offered as design ideas. It is the responsibility of the user to ensure that the circuit is fit for the user's application and meets with the user's requirements. No representation or warranty is given and no liability whatsoever is assumed by Zetex with respect to the accuracy or use of such information, or infringement of patents or other intellectual property rights arising from such use or otherwise. Zetex does not assume any legal responsibility or will not be held legally liable (whether in contract, tort (including negligence), breach of statutory duty, restriction or otherwise) for any damages, loss of profit, business, contract, opportunity or consequential loss in the use of these circuit applications, under any circumstances.

Life support

Zetex products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Zetex Semiconductors plc. As used herein:

A. Life support devices or systems are devices or systems which:

- 1. are intended to implant into the body
- or
- 2. support or sustain life and whose failure to perform when properly used in accordance with instructions
 - for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Reproduction

The product specifications contained in this publication are issued to provide outline information only which (unless agreed by the company in writing) may not be used, applied or reproduced for any purpose or form part of any order or contract or be regarded as a representation relating to the products or services concerned.

Terms and Conditions

All products are sold subjects to Zetex' terms and conditions of sale, and this disclaimer (save in the event of a conflict between the two when the terms of the contract shall prevail) according to region, supplied at the time of order acknowledgement.

For the latest information on technology, delivery terms and conditions and prices, please contact your nearest Zetex sales office.

Quality of product

Zetex is an ISO 9001 and TS16949 certified semiconductor manufacturer.

To ensure quality of service and products we strongly advise the purchase of parts directly from Zetex Semiconductors or one of our regionally authorized distributors. For a complete listing of authorized distributors please visit: www.zetex.com/salesnetwork

Zetex Semiconductors does not warrant or accept any liability whatsoever in respect of any parts purchased through unauthorized sales channels.

ESD (Electrostatic discharge)

Semiconductor devices are susceptible to damage by ESD. Suitable precautions should be taken when handling and transporting devices. The possible damage to devices depends on the circumstances of the handling and transporting, and the nature of the device. The extent of damage can vary from immediate functional or parametric malfunction to degradation of function or performance in use over time. Devices suspected of being affected should be replaced.

Green compliance

Zetex Semiconductors is committed to environmental excellence in all aspects of its operations which includes meeting or exceeding regulatory requirements with respect to the use of hazardous substances. Numerous successful programs have been implemented to reduce the use of hazardous substances and/or emissions.

All Zetex components are compliant with the RoHS directive, and through this it is supporting its customers in their compliance with WEEE and ELV directives.

Product status key:

- "Preview"Future device intended for production at some point. Samples may be available
- "Active"Product status recommended for new designs
- "Last time buy (LTB)"Device will be discontinued and last time buy period and delivery is in effect
- "Not recommended for new designs"Device is still in production to support existing designs and production
- "Obsolete"Production has been discontinued

Datasheet status key:

- "Draft version"This term denotes a very early datasheet version and contains highly provisional
- information, which may change in any manner without notice.
- "Provisional version"This term denotes a pre-release datasheet. It provides a clear indication of anticipated performance. However, changes to the test conditions and specifications may occur, at any time and without notice.
- "Issue"This term denotes an issued datasheet containing finalized specifications. However, changes to specifications may occur, at any time and without notice.



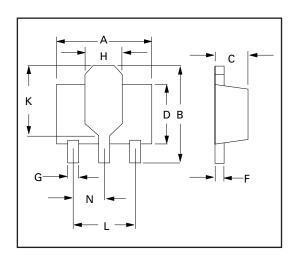
PACKAGE DIMENSIONS

DIM	Millimetres		Inc	hes
	Min	Max	Min	Max
А	4.40	4.60	0.173	0.181
В	3.75	4.25	0.150	0.167
С	1.40	1.60	0.550	0.630
D	-	2.60	-	0.102
F	0.28	0.45	0.011	0.018
G	0.38	0.55	0.015	0.022
Н	1.50	1.80	0.060	0.072
K	2.60	2.85	0.102	0.112
L	2.90	3.10	0.114	0.122
N	1.40	1.60	0.055	0.063

2.4 4.0 1.5 1.5

PAD LAYOUT DETAILS

SOT89 pattern.
Minimum Pad Size (dimensions in mm)



© Zetex Semiconductors plc 2007

Europe	Americas	Asia Pacific	Corporate Headquarters
Zetex GmbH	Zetex Inc	Zetex (Asia) Ltd	Zetex Semiconductors plc
Streitfeldstraße 19	700 Veterans Memorial Hwy	3701-04 Metroplaza Tower 1	Zetex Technology Park
D-81673 München	Hauppauge, NY 11788	Hing Fong Road, Kwai Fong	Chadderton, Oldham, OL9 9LL
Germany	USA	Hong Kong	United Kingdom
Telefon: (49) 89 45 49 49 0	Telephone: (1) 631 360 2222	Telephone: (852) 26100 611	Telephone (44) 161 622 4444
Fax: (49) 89 45 49 49	Fax: (1) 631 360 8222	Fax: (852) 24250 494	Fax: (44) 161 622 4446
europe.sales@zetex.com	usa.sales@zetex.com	asia.sales@zetex.com	hq@zetex.com





Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Diodes Incorporated: ZVP4525ZTA